

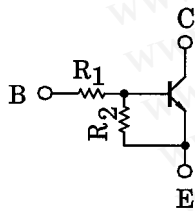
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1414,RN1415,RN1416 RN1417,RN1418

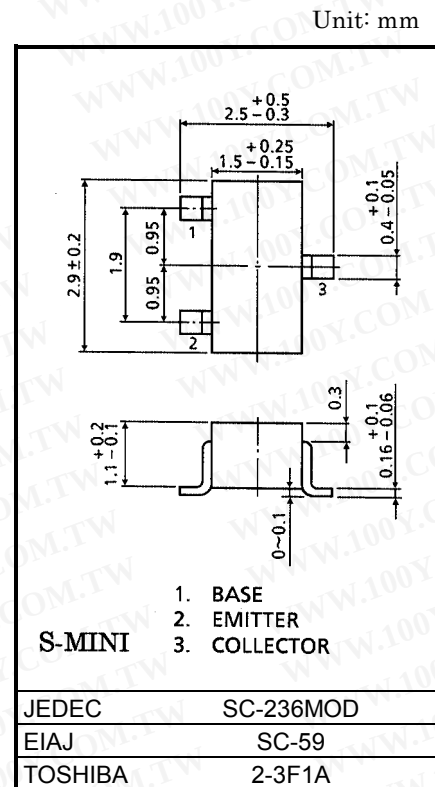
Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2414~RN2418

Equivalent Circuit and Bias Resister Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1414	1	10
RN1415	2.2	10
RN1416	4.7	10
RN1417	10	4.7
RN1418	47	10



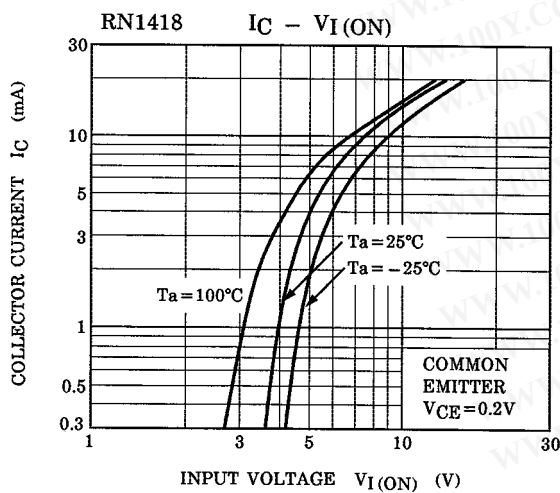
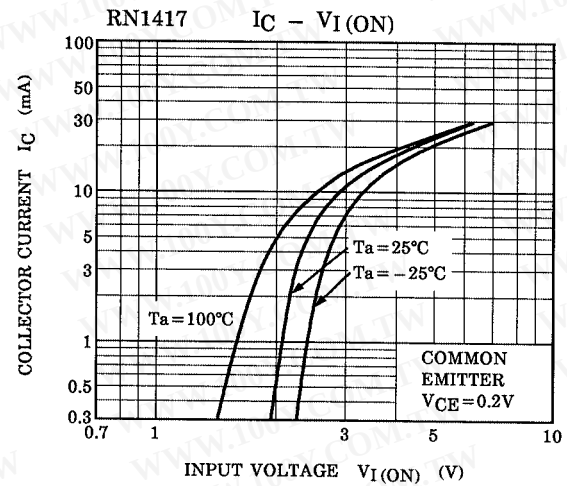
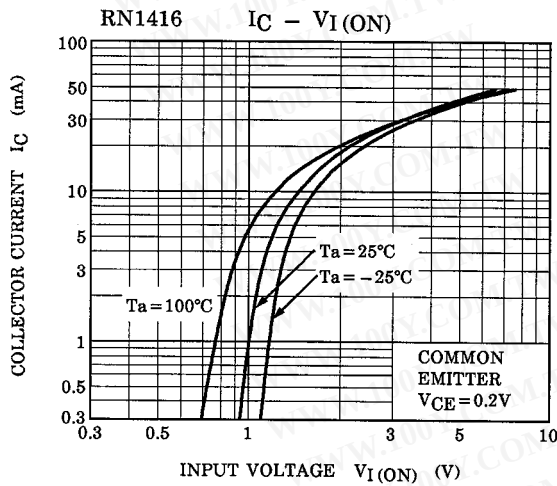
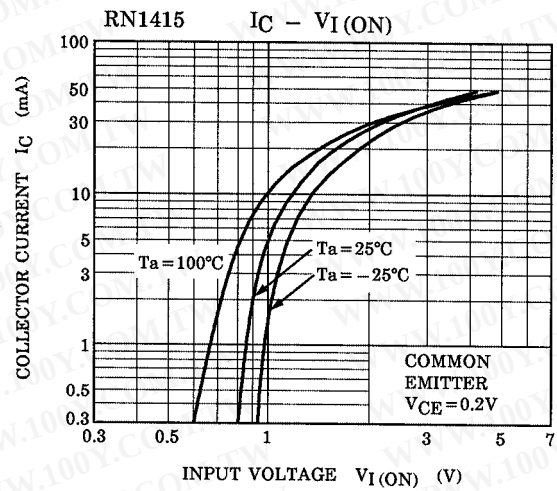
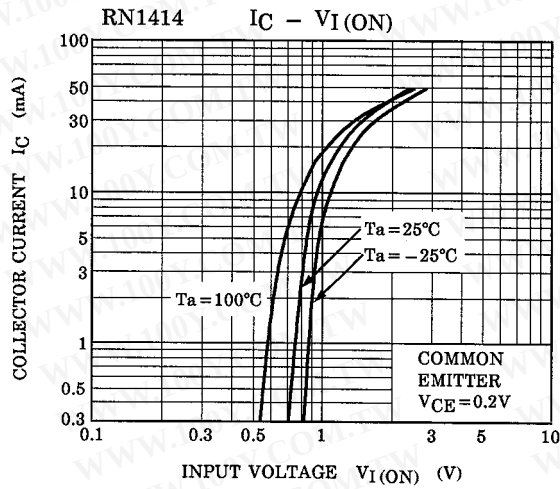
Weight: 0.012g

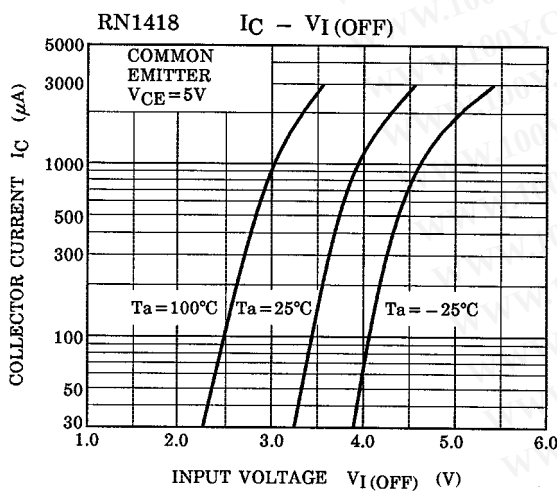
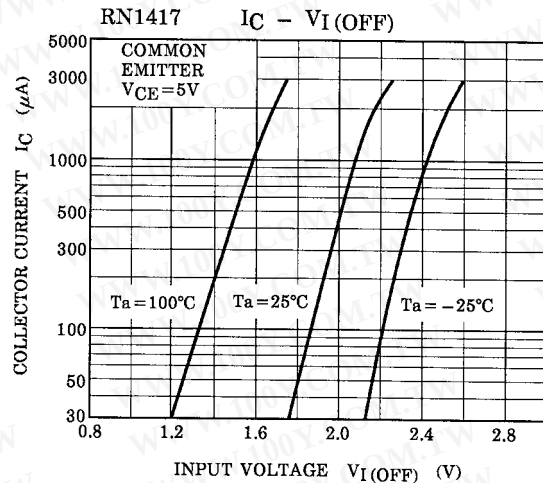
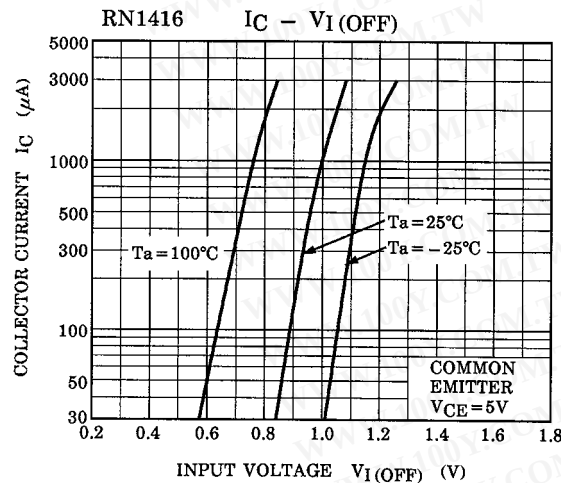
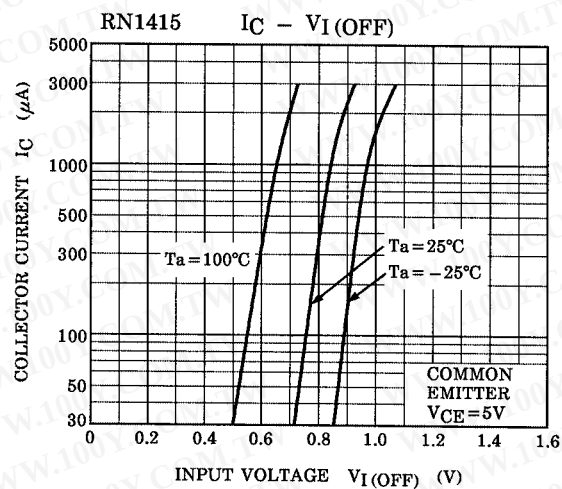
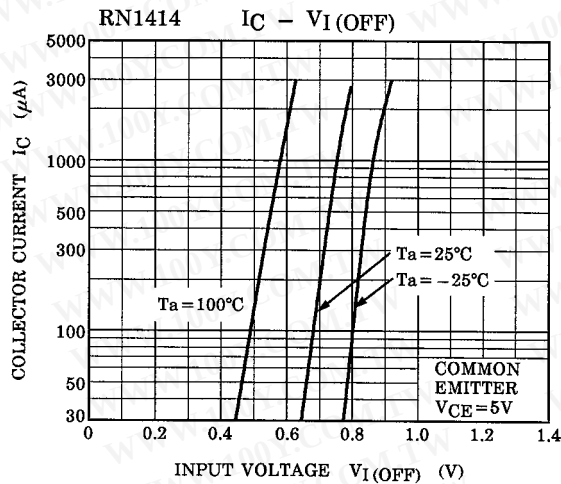
Maximum Ratings (Ta = 25°C)

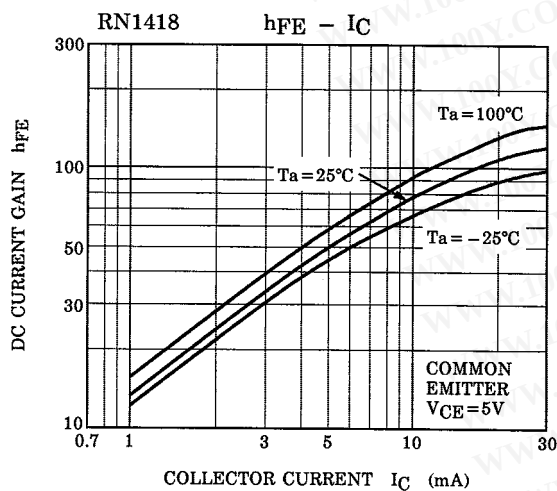
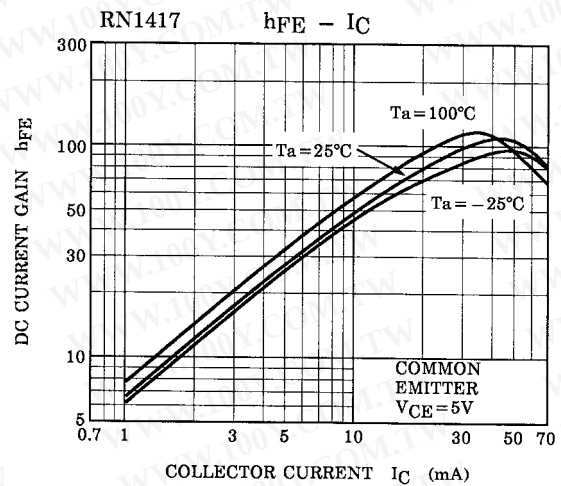
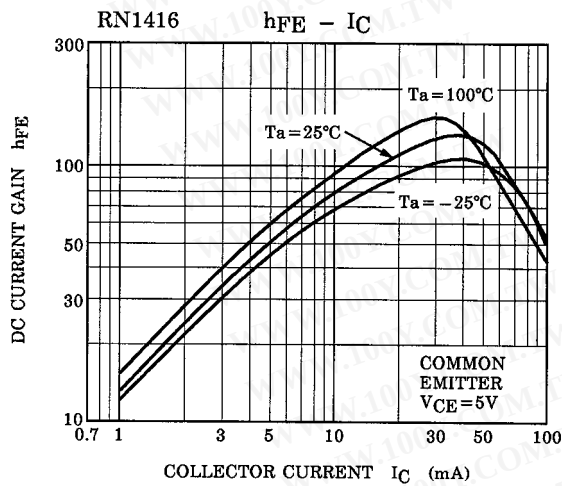
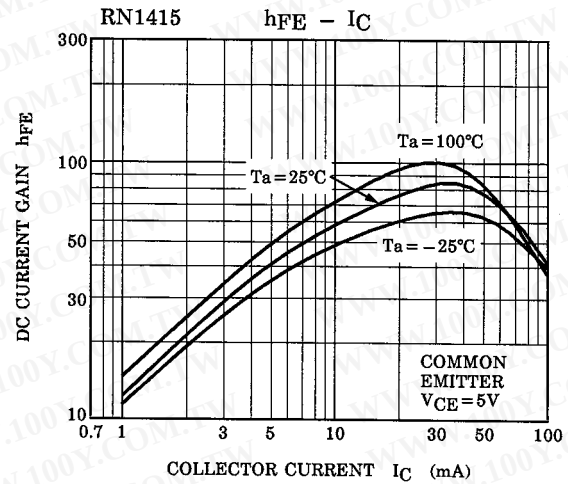
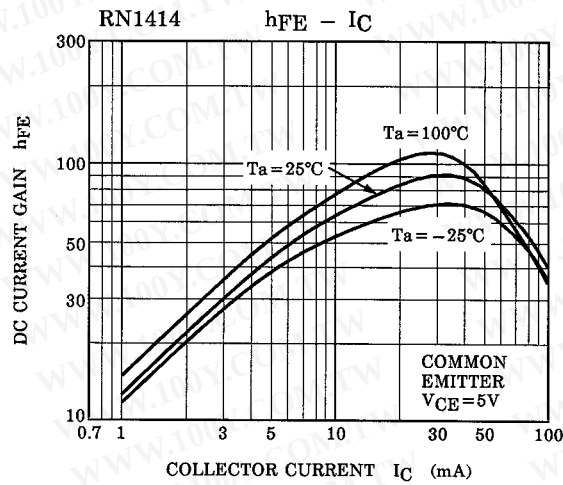
Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	RN1414	5	V
	RN1415	6	
	RN1416	7	
	RN1417	15	
	RN1418	25	
Collector current	I_C	100	mA
Collector power dissipation	P_C	200	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55~150	°C

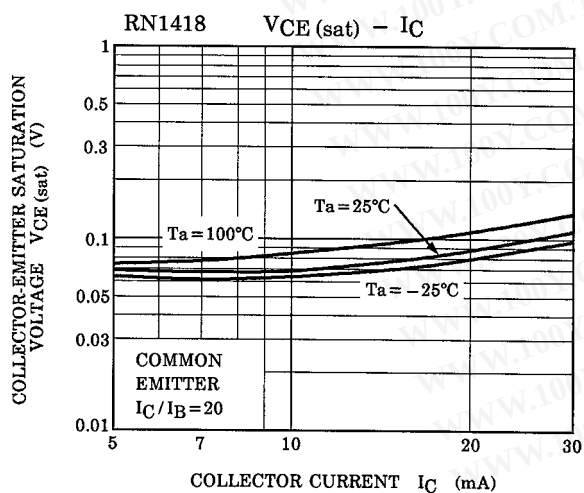
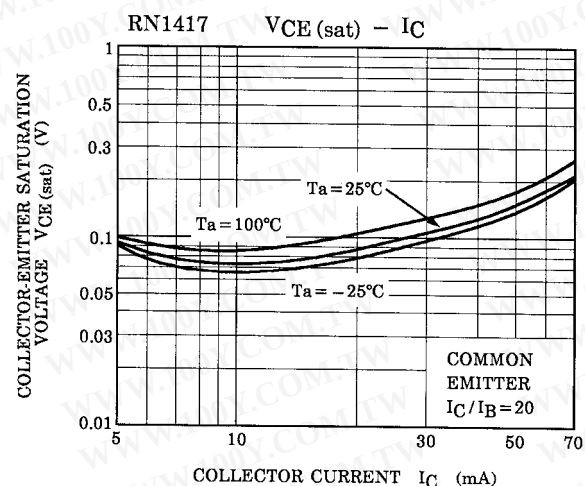
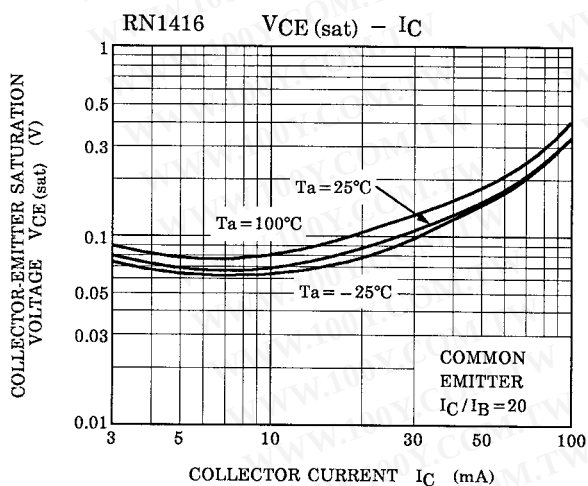
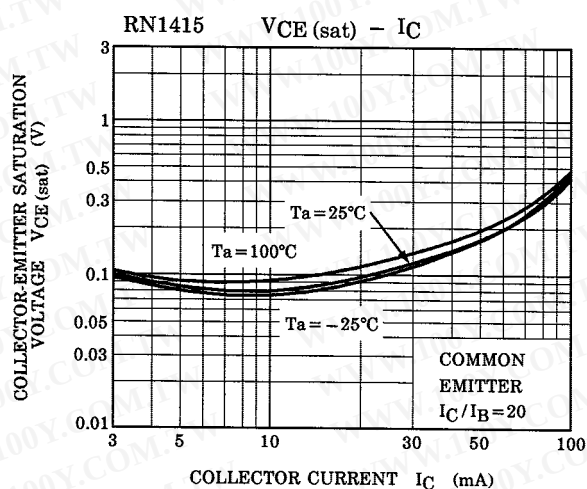
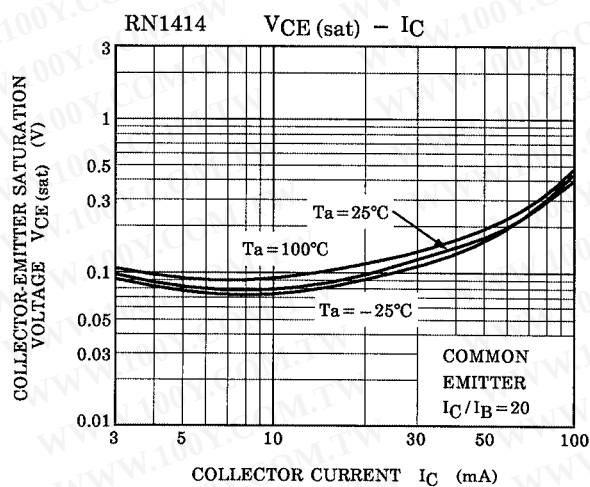
Electrical Characteristics (Ta = 25°C)

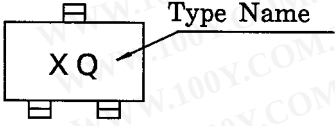
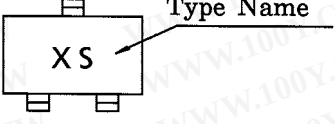
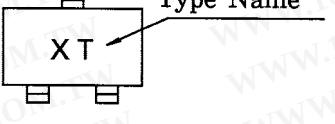
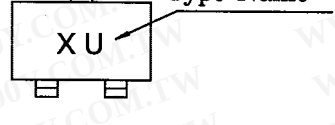
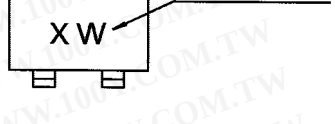
Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1414~1418	I_{CBO}	—	$V_{CB} = 50V, I_E = 0$	—	—	100	nA
	RN1414~1418	I_{CEO}		$V_{CE} = 50V, I_B = 0$	—	—	500	nA
Emitter cut-off current	RN1414	I_{EBO}	—	$V_{EB} = 5V, I_C = 0$	0.35	—	0.65	mA
	RN1415			$V_{EB} = 6V, I_C = 0$	0.37	—	0.71	
	RN1416			$V_{EB} = 7V, I_C = 0$	0.36	—	0.68	
	RN1417			$V_{EB} = 15V, I_C = 0$	0.78	—	1.46	
	RN1418			$V_{EB} = 25V, I_C = 0$	0.33	—	0.63	
DC current gain	RN1414~16, 18	h_{FE}	—	$V_{CE} = 5V, I_C = 10mA$	50	—	—	
	RN1417				30	—	—	
Collector-emitter saturation voltage	RN1414~1418	$V_{CE(sat)}$	—	$I_C = 5mA, I_B = 0.25mA$	—	0.1	0.3	V
Input voltage (ON)	RN1414	$V_I(ON)$	—	$V_{CE} = 0.2V, I_C = 5mA$	0.6	—	2.0	V
	RN1415				0.7	—	2.5	
	RN1416				0.8	—	2.5	
	RN1417				1.5	—	3.5	
	RN1418				2.5	—	10.0	
Input voltage (OFF)	RN1414	$V_I(OFF)$	—	$V_{CE} = 5V, I_C = 0.1mA$	0.3	—	0.9	V
	RN1415				0.3	—	1.0	
	RN1416				0.3	—	1.1	
	RN1417				0.3	—	2.3	
	RN1418				0.5	—	5.7	
Transition frequency	RN1414~1418	f_T	—	$V_{CE} = 10V, I_C = 5mA$	—	250	—	MHz
Collector Output capacitance	RN1414~1418	C_{ob}	—	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	3.0	6.0	pF
Input resistor	RN1414	R1	—	—	0.7	1.0	1.3	kΩ
	RN1415				1.54	2.2	2.86	
	RN1416				3.29	4.7	6.11	
	RN1417				7.0	10.0	13.0	
	RN1418				32.9	47.0	61.1	
Resistor ratio	RN1414	R1/R2	—	—	—	0.1	—	
	RN1415				—	0.22	—	
	RN1416				—	0.47	—	
	RN1417				—	2.13	—	
	RN1418				—	4.7	—	









Type Name	Marking
RN1414	
RN1415	
RN1416	
RN1417	
RN1418	

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